Applications

• High-speed switching

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

A6
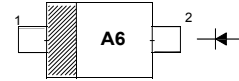
Absolute Maximum Ratings (T_a = 25 $^{\circ}$C)

Parameter		Symbol	Value	Unit
Repetitive Peak Reverse Voltage		V_{RRM}	100	V
Reverse Voltage		V_R	100	V
Continuous Forward Current		I_F	250	mA
Repetitive Peak Forward Current		I_{FRM}	500	mA
Non-Repetitive Peak Forward Current	t = 1 µs t = 1 ms t = 1 s	I_{FSM}	4 1 0.5	A
Total Power Dissipation		P_{tot}	200	mW
Junction Temperature		T_j	150	$^{\circ}$C
Storage Temperature Range		T_{stg}	- 65 to + 150	$^{\circ}$C

Characteristics at T_a = 25 $^{\circ}$C

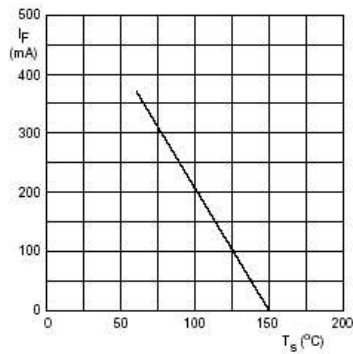| Parameter	Symbol	Max.	Unit
Forward Voltage at I_F = 1 mA at I_F = 10 mA at I_F = 50 mA at I_F = 150 mA	V_F	0.715 0.855 1 1.25	V
Reverse Current at V_R = 25 V at V_R = 75 V at V_R = 25 V, T_J = 150 $^{\circ}$C at V_R = 75 V, T_J = 150 $^{\circ}$C	I_R	30 1 30 50	nA µA µA µA
Diode Capacitance at V_R = 0 V, f = 1 MHz	C_{tot}	1.5	pF
Reverse Recovery Time at I_F = I_R = 10 mA, I_{rr} = 0.1 X I_R , R_L = 100 Ω	t_{rr}	4	ns

Typical Characteristics

Fig. 1 Maximum permissible continuous forward current as a function of soldering point temperature.
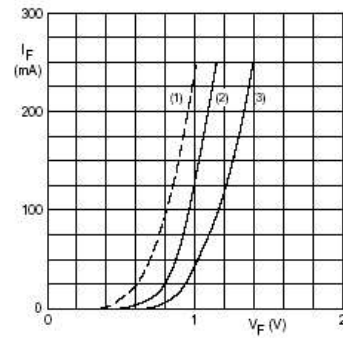
(1) T_j = 150 °C; typical values.
(2) T_j = 25 °C; typical values.
(3) T_j = 25 °C; maximum values.

Fig. 2 Forward current as a function of forward voltage.
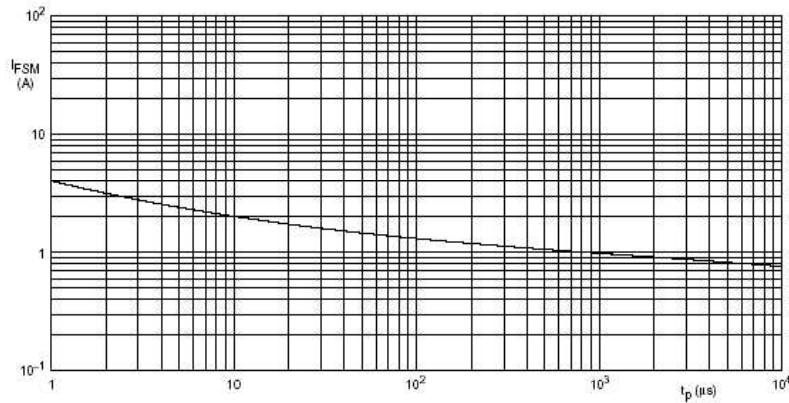
Based on square wave currents.
T_j = 25 °C prior to surge.

Fig. 3 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

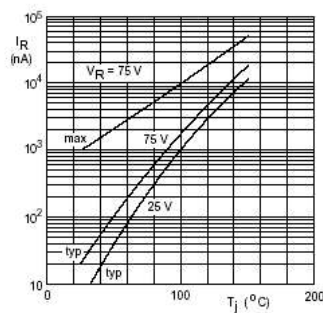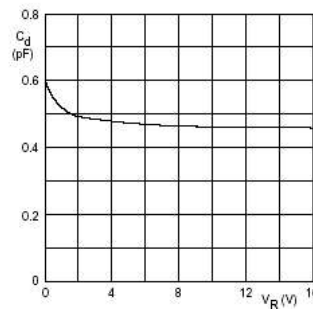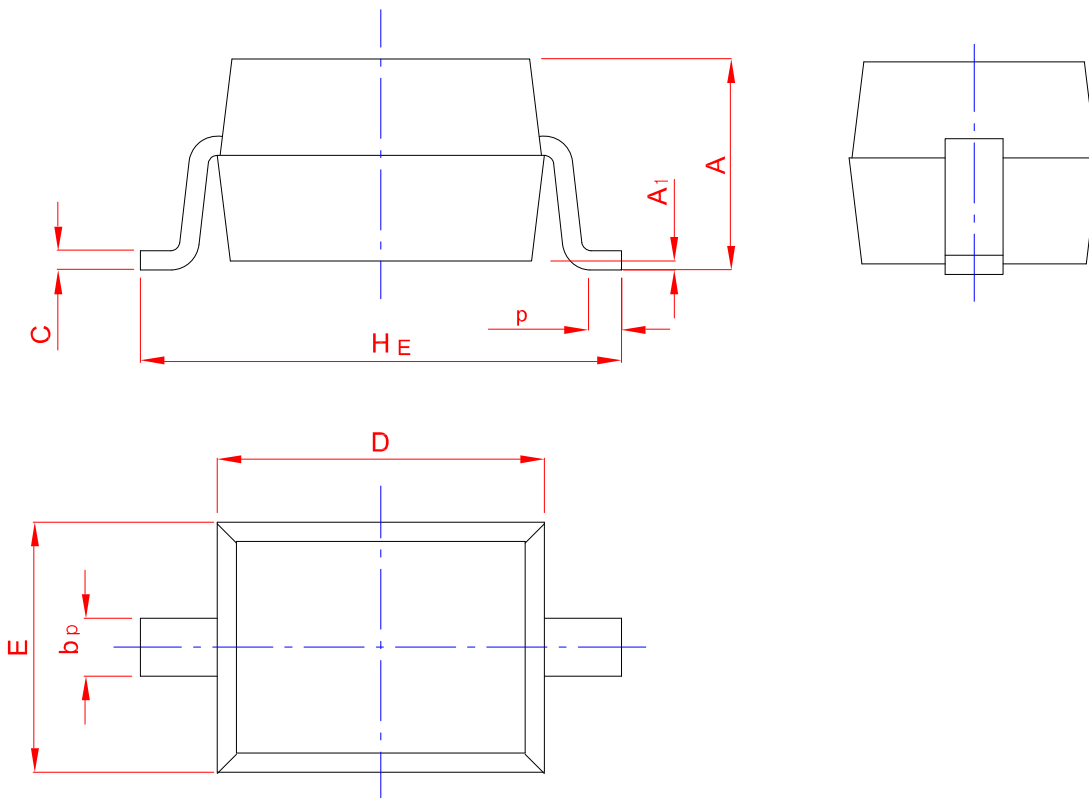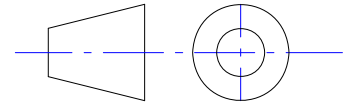Fig. 4 Reverse current as a function of junction temperature.

f = 1 MHz; T_j = 25 °C.

Fig. 5 Diode capacitance as a function of reverse voltage; typical values.

PACKAGE OUTLINE

Plastic surface mounted package; 2 leads　　　　　　　　　　**SOD-323**

UNIT	A	bp	C	D	E	HE	A1	Lp
mm	1.20 0.90	0.40 0.25	0.15 0.10	1.80 1.60	1.35 1.15	2.80 2.30	0.10 0.01	0.50 0.20